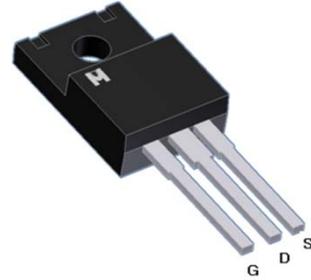
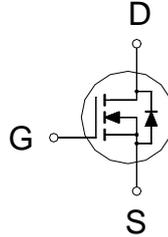


**N-Channel Logic Level Enhancement Mode Field Effect Transistor**

**Product Summary:**

$BV_{DSS}$	60V
$R_{DS(on) (MAX.)}$	4.1m $\Omega$
$I_D$	90A



UIS, Rg 100% Tested

Pb-Free Lead Plating & Halogen Free



**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNIT
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C = 25\text{ }^\circ\text{C}$	$I_D$	90	A
	$T_C = 100\text{ }^\circ\text{C}$		56	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	200	
Avalanche Current		$I_{AS}$	50	
Avalanche Energy	$L = 0.1\text{mH}, I_D = 50\text{A}, R_G = 25\Omega$	$E_{AS}$	125	mJ
Repetitive Avalanche Energy <sup>2</sup>	$L = 0.05\text{mH}$	$E_{AR}$	62.5	
Power Dissipation	$T_C = 25\text{ }^\circ\text{C}$	$P_D$	56	W
	$T_C = 100\text{ }^\circ\text{C}$		22	
Operating Junction & Storage Temperature Range		$T_{j}, T_{stg}$	-55 to 150	$^\circ\text{C}$

100% UIS testing in condition of  $V_D = 30\text{V}$ ,  $L = 0.1\text{mH}$ ,  $V_G = 10\text{V}$ ,  $I_L = 30\text{A}$ , Rated  $V_{DS} = 60\text{V}$  N-CH

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Case	$R_{\theta JC}$		2.2	$^\circ\text{C} / \text{W}$
Junction-to-Ambient	$R_{\theta JA}$		62.5	

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$



ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25 °C, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	60			V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	3.0	3.9	4.5	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V			1	μA
		V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V, T <sub>J</sub> = 125 °C			25	
On-State Drain Current <sup>1</sup>	I <sub>D(ON)</sub>	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 10V	90			A
Drain-Source On-State Resistance <sup>1</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 24A		3.5	4.1	mΩ
Forward Transconductance <sup>1</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 5V, I <sub>D</sub> = 20A		57		S
<b>DYNAMIC</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 30V, f = 1MHz		3260		pF
Output Capacitance	C <sub>oss</sub>			965		
Reverse Transfer Capacitance	C <sub>rss</sub>			155		
Gate Resistance	R <sub>g</sub>	V <sub>GS</sub> = 15mV, V <sub>DS</sub> = 0V, f = 1MHz		2.5		Ω
Total Gate Charge <sup>1,2</sup>	Q <sub>g</sub>	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 10V, I <sub>D</sub> = 24A		46		nC
Gate-Source Charge <sup>1,2</sup>	Q <sub>gs</sub>			18		
Gate-Drain Charge <sup>1,2</sup>	Q <sub>gd</sub>			12		
Turn-On Delay Time <sup>1,2</sup>	t <sub>d(on)</sub>	V <sub>DS</sub> = 30V, I <sub>D</sub> = 1A, V <sub>GS</sub> = 10V, R <sub>GS</sub> = 6Ω		55		nS
Rise Time <sup>1,2</sup>	t <sub>r</sub>			100		
Turn-Off Delay Time <sup>1,2</sup>	t <sub>d(off)</sub>			65		
Fall Time <sup>1,2</sup>	t <sub>f</sub>			120		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub> = 25 °C)</b>						
Continuous Current	I <sub>S</sub>				90	A
Pulsed Current <sup>3</sup>	I <sub>SM</sub>				200	
Forward Voltage <sup>1</sup>	V <sub>SD</sub>	I <sub>F</sub> = 24A, V <sub>GS</sub> = 0V			1.3	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 24A, dI <sub>F</sub> /dt = 100A / μS		25		nS
Reverse Recovery Charge	Q <sub>rr</sub>				125	

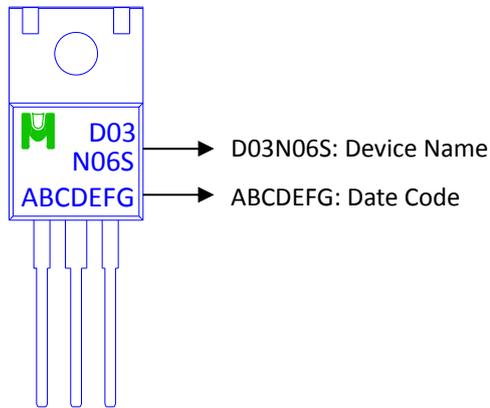
<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

<sup>2</sup>Independent of operating temperature.

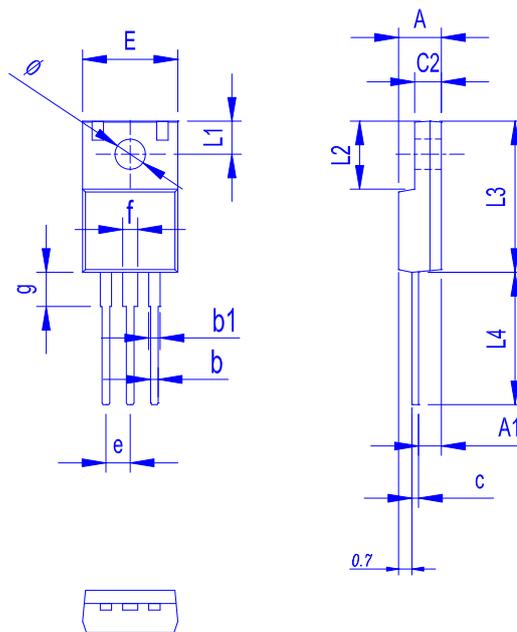
<sup>3</sup>Pulse width limited by maximum junction temperature.

Ordering & Marking Information:

Device Name: EMD03N06ES for TO-220F



Outline Drawing



Dimension in mm

Dimension	A	A1	b	b1	c	c2	E	L1	L2	L3	L4	$\phi$	e	f	g
Min.	4.20	1.95	0.50	0.90	0.45	2.34	9.70	2.70	6.48	14.80	12.50	3.00	2.35	1.18	3.13
Max.	4.90	2.96	1.05	1.50	0.80	3.20	10.36	3.80	7.50	16.30	14.50	3.60	2.75	1.90	4.00



TYPICAL CHARACTERISTICS

